

## Features

- Single Voltage Read/Write Operation: 2.65V to 3.6V
- Access Time – 70 ns
- Sector Erase Architecture
  - Sixty-three 32K Word (64K Bytes) Sectors with Individual Write Lockout
  - Eight 4K Word (8K Bytes) Sectors with Individual Write Lockout
- Fast Word Program Time – 10  $\mu$ s
- Fast Sector Erase Time – 100 ms
- Suspend/Resume Feature for Erase and Program
  - Supports Reading and Programming from Any Sector by Suspending Erase of a Different Sector
  - Supports Reading Any Word by Suspending Programming of Any Other Word
- Low-power Operation
  - 10 mA Active
  - 15  $\mu$ A Standby
- VPP Pin for Write Protection and Accelerated Program Operation
- $\overline{WP}$  Pin for Sector Protection
- $\overline{RESET}$  Input for Device Initialization
- Flexible Sector Protection
- TSOP and CBGA Package Options
- Top or Bottom Boot Block Configuration Available
- 128-bit Protection Register
- Minimum 100,000 Erase Cycles
- Common Flash Interface (CFI)
- Green (Pb/Halide-free) Packaging

## 1. Description

The AT49BV320D(T) is a 2.7-volt 32-megabit Flash memory organized as 2,097,152 words of 16 bits each. The memory is divided into 71 sectors for erase operations. The device is offered in a 48-lead TSOP package and a 47-ball CBGA package. The device has  $\overline{CE}$  and  $\overline{OE}$  control signals to avoid any bus contention. This device can be read or reprogrammed using a single power supply, making it ideally suited for in-system programming.

The device powers on in the read mode. Command sequences are used to place the device in other operation modes such as program and erase. The device has the capability to protect the data in any sector (see [“Flexible Sector Protection” on page 6](#)).

To increase the flexibility of the device, it contains an Erase Suspend and Program Suspend feature. This feature will put the erase or program on hold for any amount of time and let the user read data from or program data to any of the remaining sectors within the memory.

The VPP pin provides data protection. When the  $V_{PP}$  input is below 0.4V, the program and erase functions are inhibited. When  $V_{PP}$  is at 1.65V or above, normal program and erase operations can be performed. With  $V_{PP}$  at 10.0V, the program (Dual-word Program command) operation is accelerated.



**32-megabit  
(2M x 16)  
3-volt Only  
Flash Memory**

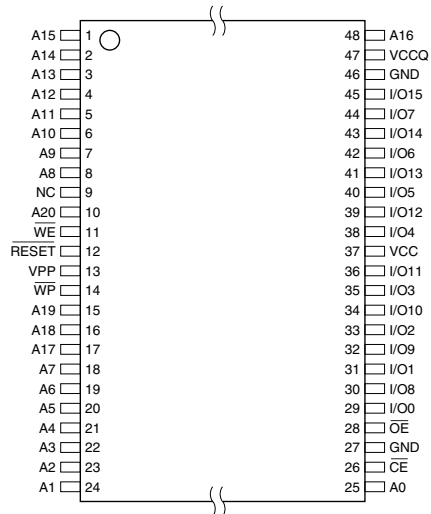
**AT49BV320D  
AT49BV320DT**



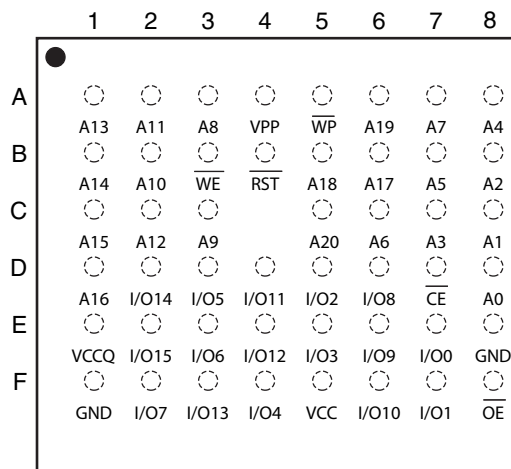
## 2. Pin Configurations

Pin Name	Function
A0 - A20	Addresses
$\overline{CE}$	Chip Enable
$\overline{OE}$	Output Enable
$\overline{WE}$	Write Enable
$\overline{RESET}$	Reset
VPP	Write Protection
I/O0 - I/O15	Data Inputs/Outputs
NC	No Connect
VCCQ	Output Power Supply
$\overline{WP}$	Write Protect

### 2.1 TSOP Top View (Type 1)



### 2.2 CBGA Top View (Ball Down)





outputs are put in the high impedance state whenever  $\overline{CE}$  or  $\overline{OE}$  is high. This dual-line control gives designers flexibility in preventing bus contention.

### 4.3 Reset

A  $\overline{RESET}$  input pin is provided to ease some system applications. When  $\overline{RESET}$  is at a logic high level, the device is in its standard operating mode. A low level on the  $\overline{RESET}$  input halts the present device operation and puts the outputs of the device in a high impedance state. When a high level is reasserted on the  $\overline{RESET}$  pin, the device returns to the read mode, depending upon the state of the control inputs.

### 4.4 Erase

Before a word can be reprogrammed, it must be erased. The erased state of memory bits is a logical "1". The individual sectors can be erased by using the Sector Erase command.

#### 4.4.1 Sector Erase

The device is organized into 71 sectors (SA0 - SA70) that can be individually erased. The Sector Erase command is a two-bus cycle operation. The sector address and the D0H Data Input command are latched on the rising edge of  $\overline{WE}$ . The sector erase starts after the rising edge of  $\overline{WE}$  of the second cycle provided the given sector has not been protected. The erase operation is internally controlled; it will automatically time to completion. The maximum time to erase a sector is  $t_{SEC}$ . An attempt to erase a sector that has been protected will result in the operation terminating immediately.

### 4.5 Word Programming

Once a memory sector is erased, it is programmed (to a logical "0") on a word-by-word basis. Programming is accomplished via the Internal Device command register and is a two-bus cycle operation. The device will automatically generate the required internal program pulses.

Any commands, except Read Status Register, Program Suspend and Program Resume, written to the chip during the embedded programming cycle will be ignored. If a hardware reset happens during programming, the data at the location being programmed will be corrupted. Please note that a data "0" cannot be programmed back to a "1"; only erase operations can convert "0"s to "1"s. Programming is completed after the specified  $t_{BP}$  cycle time. If the program status bit is a "1", the device was not able to verify that the program operation was performed successfully. The status register indicates the programming status. While the program sequence executes, status bit I/O7 is "0".

### 4.6 VPP Pin

The circuitry of the AT49BV320D(T) is designed so that the device cannot be programmed or erased if the  $V_{PP}$  voltage is less than 0.4V. When  $V_{PP}$  is at 1.65V or above, normal program and erase operations can be performed. The VPP pin cannot be left floating.

## 4.7 Read Status Register

The status register indicates the status of device operations and the success/failure of that operation. The Read Status Register command causes subsequent reads to output data from the status register until another command is issued. To return to reading from the memory, issue a Read command.

The status register bits are output on I/O7 - I/O0. The upper byte, I/O15 - I/O8, outputs 00H when a Read Status Register command is issued.

The contents of the status register [SR7:SR0] are latched on the falling edge of  $\overline{OE}$  or  $\overline{CE}$  (whichever occurs last), which prevents possible bus errors that might occur if status register contents change while being read.  $\overline{CE}$  or  $\overline{OE}$  must be toggled with each subsequent status read, or the status register will not indicate completion of a Program or Erase operation.

When the Write State Machine (WSM) is active, SR7 will indicate the status of the WSM; the remaining bits in the status register indicate whether the WSM was successful in performing the preferred operation (see [Table 4-1](#)).

**Table 4-1.** Status Register Bit Definition

WSMS	ESS	ES	PS	VPPS	PSS	SLS	R
7	6	5	4	3	2	1	0
				<b>Notes</b>			
SR7 WRITE STATE MACHINE STATUS (WSMS) 1 = Ready 0 = Busy				Check Write State Machine bit first to determine Word Program or Sector Erase completion, before checking program or erase status bits.			
SR6 = ERASE SUSPEND STATUS (ESS) 1 = Erase Suspended 0 = Erase In Progress/Completed				When Erase Suspend is issued, WSM halts execution and sets both WSMS and ESS bits to "1" – ESS bit remains set to "1" until an Erase Resume command is issued.			
SR5 = ERASE STATUS (ES) 1 = Error in Sector Erase 0 = Successful Sector Erase				When this bit is set to "1", WSM has applied the max number of erase pulses to the sector and is still unable to verify successful sector erasure.			
SR4 = PROGRAM STATUS (PS) 1 = Error in Programming 0 = Successful Programming				When this bit is set to "1", WSM has attempted but failed to program a word			
SR3 = VPP STATUS (VPPS) 1 = VPP Low Detect, Operation Abort 0 = VPP OK				The V <sub>PP</sub> status bit does not provide continuous indication of VPP level. The WSM interrogates V <sub>PP</sub> level only after the Program or Erase command sequences have been entered and informs the system if V <sub>PP</sub> has not been switched on. The V <sub>PP</sub> is also checked before the operation is verified by the WSM.			
SR2 = PROGRAM SUSPEND STATUS (PSS) 1 = Program Suspended 0 = Program in Progress/Completed				When Program Suspend is issued, WSM halts execution and sets both WSMS and PSS bits to "1". PSS bit remains set to "1" until a Program Resume command is issued.			
SR1 = SECTOR LOCK STATUS (SLS) 1 = Prog/Erase attempted on a locked sector; Operation aborted. 0 = No operation to locked sectors				If a Program or Erase operation is attempted to one of the locked sectors, this bit is set by the WSM. The operation specified is aborted and the device is returned to read status mode.			
SR0 = RESERVED FOR FUTURE ENHANCEMENTS (R)				This bit is reserved for future use and should be masked out when polling the status register.			

Note: 1. A Command Sequence Error is indicated when SR1, SR3, SR4 and SR5 are set.

#### 4.7.1 Clear Status Register

The WSM can set status register bits 1 through 7 and can clear bits 2, 6 and 7; but, the WSM cannot clear status register bits 1, 3, 4 or 5. Because bits 1, 3, 4 and 5 indicate various error conditions, these bits can be cleared only through the Clear Status Register command. By allowing the system software to control the resetting of these bits, several operations may be performed (such as cumulatively programming several addresses or erasing multiple sectors in sequence) before reading the status register to determine if an error occurred during those operations. The status register should be cleared before beginning another operation. The Read command must be issued before data can be read from the memory array. The status register can also be cleared by resetting the device.

#### 4.8 Flexible Sector Protection

The AT49BV320D(T) offers two sector protection modes, the Softlock and the Hardlock. The Softlock mode is optimized as sector protection for sectors whose content changes frequently. The Hardlock protection mode is recommended for sectors whose content changes infrequently. Once either of these two modes is enabled, the contents of the selected sector is read-only and cannot be erased or programmed. Each sector can be independently programmed for either the Softlock or Hardlock sector protection mode. At power-up and reset, all sectors have their Softlock protection mode enabled.

##### 4.8.1 Softlock and Unlock

The Softlock protection mode can be disabled by issuing a two-bus cycle Unlock command to the selected sector. Once a sector is unlocked, its contents can be erased or programmed. To enable the Softlock protection mode, a two-bus cycle Softlock command must be issued to the selected sector.

##### 4.8.2 Hardlock and Write Protect

The Hardlock sector protection mode operates in conjunction with the Write Protect ( $\overline{WP}$ ) pin. The Hardlock sector protection mode can be enabled by issuing a two-bus cycle Hardlock Software command to the selected sector. The state of the Write Protect pin affects whether the Hardlock protection mode can be overridden.

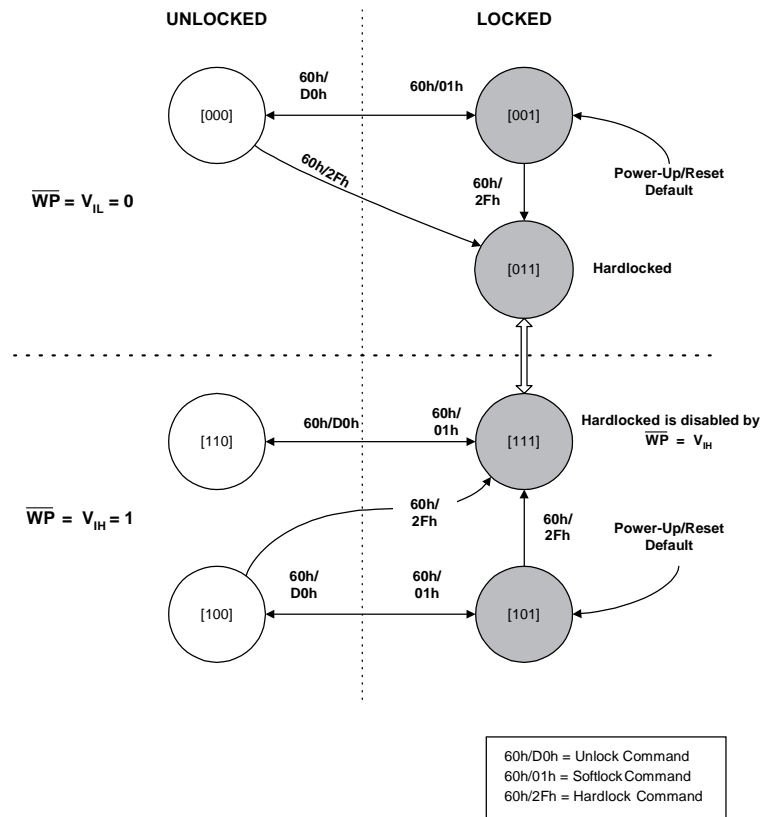
- When the  $\overline{WP}$  pin is low and the Hardlock protection mode is enabled, the sector cannot be unlocked and the contents of the sector is read-only.
- When the  $\overline{WP}$  pin is high, the Hardlock protection mode is overridden and the sector can be unlocked via the Unlock command.

To disable the Hardlock sector protection mode, the chip must be either reset or power cycled.

**Table 4-2.** Hardlock and Softlock Protection Configurations in Conjunction with  $\overline{WP}$

$V_{PP}$	$\overline{WP}$	Hard-lock	Soft-lock	Erase/ Prog Allowed?	Comments
$V_{CC}/5V$	0	0	0	Yes	No sector is locked
$V_{CC}/5V$	0	0	1	No	Sector is Softlocked. The Unlock command can unlock the sector.
$V_{CC}/5V$	0	1	1	No	Hardlock protection mode is enabled. The sector cannot be unlocked.
$V_{CC}/5V$	1	0	0	Yes	No sector is locked.
$V_{CC}/5V$	1	0	1	No	Sector is Softlocked. The Unlock command can unlock the sector.
$V_{CC}/5V$	1	1	0	Yes	Hardlock protection mode is overridden and the sector is not locked.
$V_{CC}/5V$	1	1	1	No	Hardlock protection mode is overridden and the sector can be unlocked via the Unlock command.
$V_{IL}$	x	x	x	No	Erase and Program Operations cannot be performed.

**Figure 4-1.** Sector Locking State Diagram



Note: 1. The notation [X, Y, Z] denotes the locking state of a sector. The current locking state of a sector is defined by the state of  $\overline{WP}$  and the two bits of the sector-lock status D[1:0].

### 4.8.3 Sector Protection Detection

A software method is available to determine if the sector protection Softlock or Hardlock features are enabled. When the device is in the software product identification mode, a read from the I/O0 and I/O1 at address location 00002H within a sector will show if the sector is unlocked, soft-locked, or hardlocked.

**Table 4-3.** Sector Protection Status

I/O1	I/O0	Sector Protection Status
0	0	Sector Not Locked
0	1	Softlock Enabled
1	0	Hardlock Enabled
1	1	Both Hardlock and Softlock Enabled

### 4.9 Erase Suspend/Erase Resume

The Erase Suspend command allows the system to interrupt a sector erase operation and then program or read data from a different sector within the memory. After the Erase Suspend command is given, the device requires a maximum time of 15  $\mu$ s to suspend the erase operation. After the erase operation has been suspended, the system can then read data or program data to any other sector within the device. An address is not required during the Erase Suspend command. During a sector erase suspend, another sector cannot be erased. To resume the sector erase operation, the system must write the Erase Resume command. The Erase Resume command is a one-bus cycle command. The only valid commands while erase is suspended are Read Status Register, Product ID Entry, CFI Query, Program, Program Resume, Erase Resume, Sector Softlock/Hardlock, Sector Unlock.

### 4.10 Program Suspend/Program Resume

The Program Suspend command allows the system to interrupt a programming operation and then read data from a different word within the memory. After the Program Suspend command is given, the device requires a maximum of 20  $\mu$ s to suspend the programming operation. After the programming operation has been suspended, the system can then read data from any other word within the device. An address is not required during the program suspend operation. To resume the programming operation, the system must write the Program Resume command. The program suspend and resume are one-bus cycle commands. The command sequence for the erase suspend and program suspend are the same and the command sequence for the erase resume and program resume are the same. The only other valid commands while program is suspended are Read Status Register, Product ID Entry, CFI Query and Program Resume.

### 4.11 Product Identification

The product identification mode identifies the device and manufacturer as Atmel. It may be accessed by a software operation. For details, see [“Operating Modes” on page 21](#).

### 4.12 128-bit Protection Register

The AT49BV320D(T) contains a 128-bit register that can be used for security purposes in system design. The protection register is divided into two 64-bit sectors. The two sectors are designated as sector A and sector B. The data in sector A is non-changeable and is programmed at the factory with a unique number. The data in sector B is programmed by the user and can be locked out such that data in the sector cannot be reprogrammed. To program sector

B in the protection register, the two-bus cycle Program Protection Register command must be used as shown in the “[Command Definition Table](#)” on page 15. To lock out sector B, the two-bus cycle Lock Protection Register command must be used as shown in the “[Command Definition Table](#)”. Data bit D1 must be zero during the second bus cycle. All other data bits during the second bus cycle are don't cares. To determine whether sector B is locked out, use the status of sector B protection command. If data bit D1 is zero, sector B is locked. If data bit D1 is one, sector B can be reprogrammed. Please see the “[Protection Register Addressing Table](#)” on page 16 for the address locations in the protection register. To read the protection register, the Product ID Entry command is given followed by a normal read operation from an address within the protection register. After determining whether sector B is protected or not, or reading the protection register, the Read command must be given to return to the read mode.

#### 4.13 Common Flash Interface (CFI)

CFI is a published, standardized data structure that may be read from a flash device. CFI allows system software to query the installed device to determine the configurations, various electrical and timing parameters and functions supported by the device. CFI is used to allow the system to learn how to interface to the flash device most optimally. The two primary benefits of using CFI are ease of upgrading and second source availability. The command to enter the CFI Query mode is a one-bus cycle command which requires writing data 98h to any address. The CFI Query command can be written when the device is ready to read data or can also be written when the part is in the product ID mode. Once in the CFI Query mode, the system can read CFI data at the addresses given in “[Common Flash Interface Definition Table](#)” on page 27. To return to the read mode, issue the Read command.

#### 4.14 Hardware Data Protection

The Hardware Data Protection feature protects against inadvertent programs to the AT49BV320D(T) in the following ways: (a)  $V_{CC}$  sense: if  $V_{CC}$  is below 1.8V (typical), the program function is inhibited. (b)  $V_{CC}$  power-on delay: once  $V_{CC}$  has reached the  $V_{CC}$  sense level, the device will automatically time out 10 ms (typical) before programming. (c) Program inhibit: holding any one of  $\overline{OE}$  low,  $\overline{CE}$  high or  $\overline{WE}$  high inhibits program cycles. (d) Program inhibit:  $V_{PP}$  is less than  $V_{ILPP}$ .

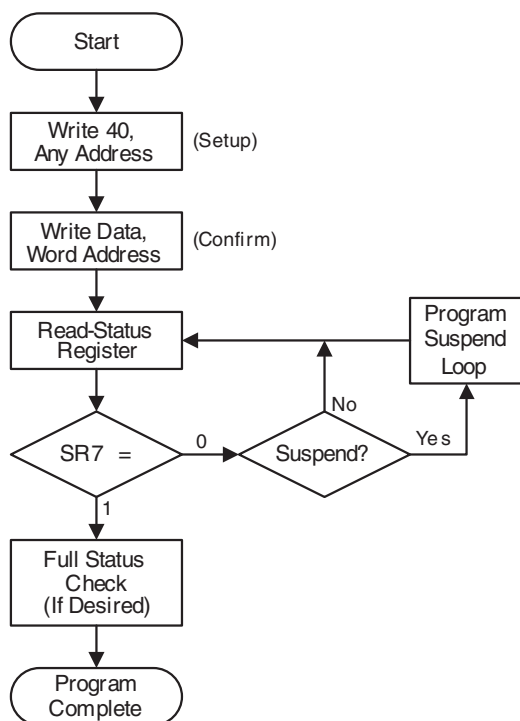
#### 4.15 Input Levels

While operating with a 2.65V to 3.6V power supply, the address inputs and control inputs ( $\overline{OE}$ ,  $\overline{CE}$  and  $\overline{WE}$ ) may be driven from 0 to 5.5V without adversely affecting the operation of the device. The I/O lines can only be driven from 0 to  $V_{CCQ} + 0.6V$ .

#### 4.16 Output Levels

For the AT49BV320D(T), output high levels ( $V_{OH}$ ) are equal to  $V_{CCQ} - 0.1V$  (not  $V_{CC}$ ). For 2.65V - 3.6V output levels,  $V_{CCQ}$  must be tied to  $V_{CC}$ .

## 5. Word Program Flowchart

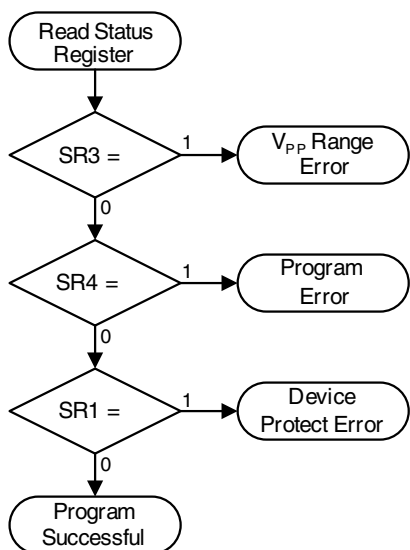


## 6. Word Program Procedure

Bus Operation	Command	Comments
Write	Program Setup	Data = 40 Addr = Any Address
Write	Data	Data = Data to program Addr = Location to program
Read	None	Status register data: Toggle $\overline{CE}$ or $\overline{OE}$ to update status register
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy

Repeat for subsequent Word Program operations.  
Full status register check can be done after each program, or after a sequence of program operations.  
Write FF after the last operation to set to the Read state.

## 7. Full Status Check Flowchart

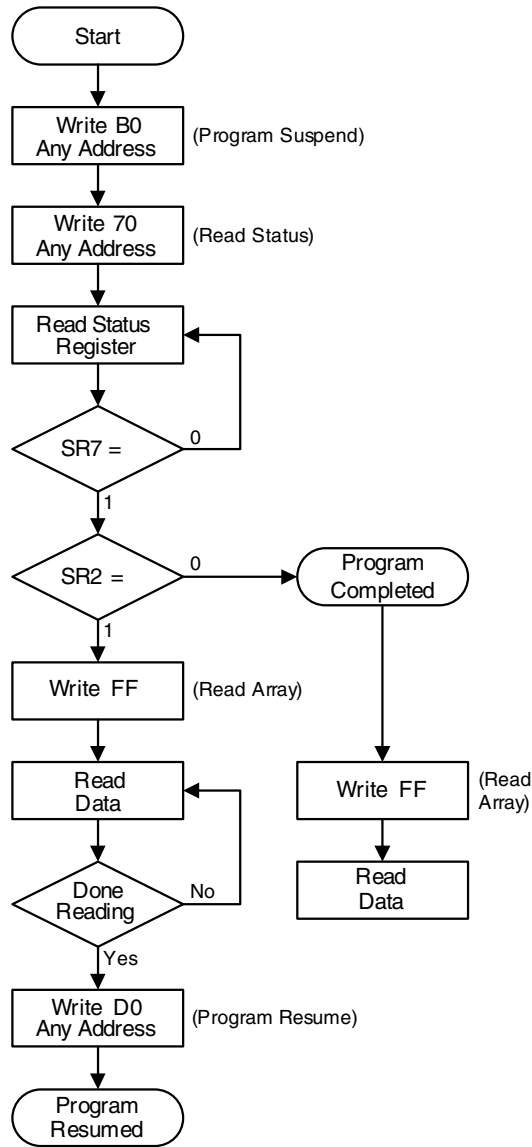


## 8. Full Status Check Procedure

Bus Operation	Command	Comments
Idle	None	Check SR3: 1 = V <sub>PP</sub> Error
Idle	None	Check SR4: 1 = Data Program Error
Idle	None	Check SR1: 1 = Sector locked; operation aborted

SR3 MUST be cleared before the Write State Machine allows further program attempts.  
If an error is detected, clear the status register before continuing operations – only the Clear Status Register command clears the status register error bits.

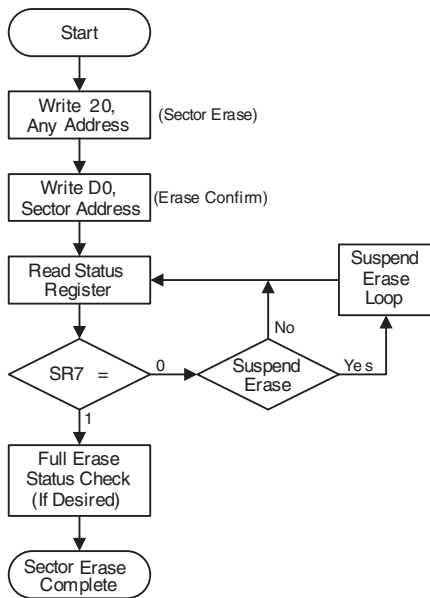
## 9. Program Suspend/Resume Flowchart



## 10. Program Suspend/Resume Procedure

Bus Operation	Command	Comments
Write	Program Suspend	Data = B0 Addr = Any address
Write	Read Status	Data = 70 Addr = Any address
Read	None	Status register data: Toggle $\overline{CE}$ or $\overline{OE}$ to update status register Addr = Any address
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy
Idle	None	Check SR2 1 = Program suspended 0 = Program completed
Write	Read Array	Data = FF Addr = Any address
Read	None	Read data from any word in the memory
Write	Program Resume	Data = D0 Addr = Any address

## 11. Sector Erase Flowchart

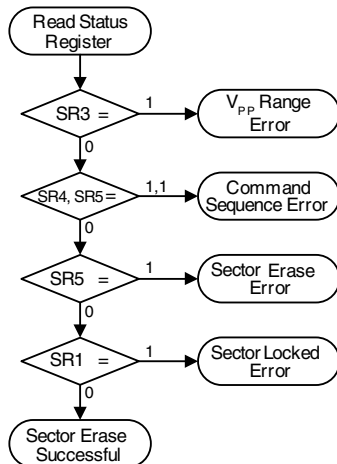


## 12. Sector Erase Procedure

Bus Operation	Command	Comments
Write	Sector Erase Setup	Data = 20 Addr = Any address
Write	Erase Confirm	Data = D0 Addr = Sector to be erased (SA)
Read	None	Status register data: Toggle $\overline{CE}$ or $\overline{OE}$ to update status register data
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy

Repeat for subsequent sector erasures.  
Full status register check can be done after each sector erase, or after a sequence of sector erasures.  
Write FF after the last operation to enter read mode.

## 13. Full Erase Status Check Flowchart

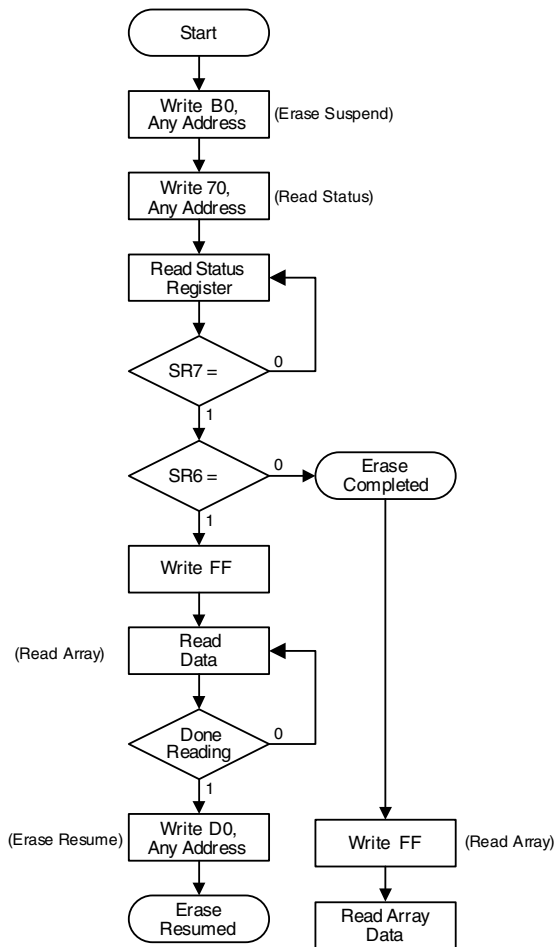


## 14. Full Erase Status Check Procedure

Bus Operation	Command	Comments
Idle	None	Check SR3: 1 = V <sub>PP</sub> Range Error
Idle	None	Check SR4, SR5: Both 1 = Command Sequence Error
Idle	None	Check SR5: 1 = Sector Erase Error
Idle	None	Check SR1: 1 = Attempted erase of locked sector; erase aborted.

SR1, SR3 must be cleared before the Write State Machine allows further erase attempts.  
Only the Clear Status Register command clears SR1, SR3, SR4, SR5.  
If an error is detected, clear the status register before attempting an erase retry or other error recovery.

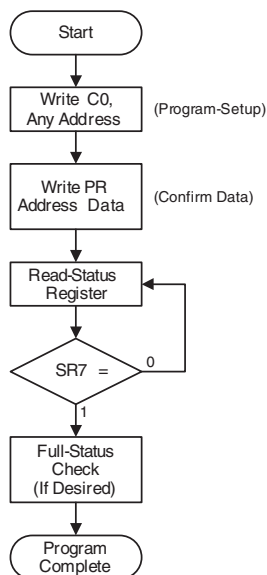
## 15. Erase Suspend/Resume Flowchart



## 16. Erase Suspend/Resume Procedure

Bus Operation	Command	Comments
Write	Erase Suspend	Data = B0 Addr = Any address
Write	Read Status	Data = 70 Addr = Any address
Read	None	Status register data: Toggle $\overline{CE}$ or $\overline{OE}$ to update status register Addr = Any address
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy
Idle	None	Check SR6 1 = Erase suspended 0 = Erase completed
Write	Read or Program	Data = FF or 40 Addr = Any address
Read or Write	None	Read or program data from/to sector other than the one being erased
Write	Program Resume	Data = D0 Addr = Any address

## 17. Protection Register Programming Flowchart



## 18. Protection Register Programming Procedure

Bus Operation	Command	Comments
Write	Program PR Setup	Data = C0 Addr = Any address
Write	Protection Program	Data = Data to Program Addr = Location to Program
Read	None	Status register data: Toggle $\overline{CE}$ or $\overline{OE}$ to update status register data
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy

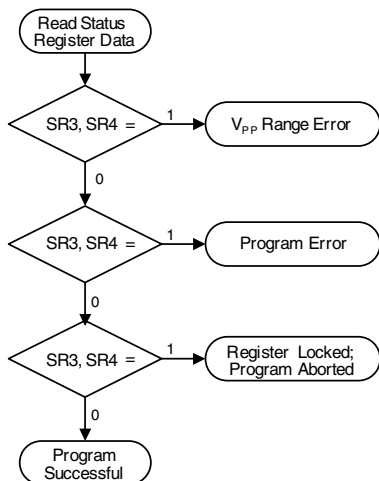
Program Protection Register operation addresses must be within the protection register address space. Addresses outside this space will return an error.

Repeat for subsequent programming operations.

Full status register check can be done after each program, or after a sequence of program operations.

Write FF after the last operation to return to the Read mode.

## 19. Full Status Check Flowchart



## 20. Full Status Check Procedure

Bus Operation	Command	Comments
Idle	None	Check SR1, SR3, SR4: 0,1,1 = $V_{PP}$ Range Error
Idle	None	Check SR1, SR3, SR4: 0,0,1 = Programming Error
Idle	None	Check SR1, SR3, SR4: 1, 0,1 = Sector locked; operation aborted

SR3 must be cleared before the Write State Machine allows further program attempts.

Only the Clear Status Register command clears SR1, SR3, SR4.

If an error is detected, clear the status register before attempting a program retry or other error recovery.

## 21. Command Definition Table

Command Sequence	Bus Cycles	1st Bus Cycle		2nd Bus Cycle		3rd Bus Cycle	
		Addr	Data	Addr	Data	Addr	Data
Read	1	XX	FF				
Sector Erase/Confirm	2	XX	20	SA <sup>(2)</sup>	D0		
Word Program	2	XX	40/10	Addr	D <sub>IN</sub>		
Dual-word Program <sup>(3)</sup>	3	XX	E0	Addr0	D <sub>IN0</sub>	Addr1	D <sub>IN1</sub>
Erase/Program Suspend	1	XX	B0				
Erase/Program Resume	1	XX	D0				
Product ID Entry	1	XX	90				
Sector Softlock	2	XX	60	SA <sup>(2)</sup>	01		
Sector Hardlock	2	XX	60	SA <sup>(2)</sup>	2F		
Sector Unlock	2	XX	60	SA <sup>(2)</sup>	D0		
Read Status Register	2	XX	70	XX	D <sub>OUT</sub> <sup>(4)</sup>		
Clear Status Register	1	XX	50				
Program Protection Register	2	XX	C0	Addr <sup>(5)</sup>	D <sub>IN</sub>		
Lock Protection Register – Sector B	2	XX	C0	80	FFFD		
Status of Sector B Protection	2	XX	90	80	D <sub>OUT</sub> <sup>(6)</sup>		
CFI Query	1	XX	98				

- Notes:
1. The DATA FORMAT shown for each bus cycle is as follows; I/O7 - I/O0 (Hex). I/O15 - I/O8 are don't care. The ADDRESS FORMAT shown for each bus cycle is as follows: A7 - A0 (Hex). Address A20 through A8 are don't care.
  2. SA = sector address. Any word address within a sector can be used to designate the sector address (see pages 17 - 20 for details).
  3. This fast programming option enables the user to program two words in parallel only when V<sub>PP</sub> = 9.5V. The addresses, Addr0 and Addr1, of the two words, D<sub>IN0</sub> and D<sub>IN1</sub>, must only differ in address A0. This command should be used during manufacturing purposes only.
  4. The status register bits are output on I/O7 - I/O0.
  5. Any addresses within the user programmable protection register region. Address locations are shown on “[Protection Register Addressing Table](#)” on page 16.
  6. If data bit D1 is “0”, sector B is locked. If data bit D1 is “1”, sector B can be reprogrammed.

## 22. Absolute Maximum Ratings\*

Temperature under Bias .....	-55°C to +125°C
Storage Temperature .....	-65°C to +150°C
All Input Voltages (including NC Pins) with Respect to Ground .....	-0.6V to +6.25V
All Output Voltages with Respect to Ground .....	-0.6V to V <sub>CC</sub> + 0.6V
Voltage on V <sub>PP</sub> with Respect to Ground .....	-0.6V to +10.0V

**\*NOTICE:** Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## 23. Protection Register Addressing Table

Address	Use	Sector	A7	A6	A5	A4	A3	A2	A1	A0
81	Factory	A	1	0	0	0	0	0	0	1
82	Factory	A	1	0	0	0	0	0	1	0
83	Factory	A	1	0	0	0	0	0	1	1
84	Factory	A	1	0	0	0	0	1	0	0
85	User	B	1	0	0	0	0	1	0	1
86	User	B	1	0	0	0	0	1	1	0
87	User	B	1	0	0	0	0	1	1	1
88	User	B	1	0	0	0	1	0	0	0

Note: All address lines not specified in the above table must be "0" when accessing the protection register, i.e., A20 - A8 = 0.

## 24. AT49BV320D Sector Address Table

Sector	Size (Bytes/Words)	Address Range (A20 - A0)
SA0	8K/4K	00000 - 00FFF
SA1	8K/4K	01000 - 01FFF
SA2	8K/4K	02000 - 02FFF
SA3	8K/4K	03000 - 03FFF
SA4	8K/4K	04000 - 04FFF
SA5	8K/4K	05000 - 05FFF
SA6	8K/4K	06000 - 06FFF
SA7	8K/4K	07000 - 07FFF
SA8	64K/32K	08000 - 0FFFF
SA9	64K/32K	10000 - 17FFF
SA10	64K/32K	18000 - 1FFFF
SA11	64K/32K	20000 - 27FFF
SA12	64K/32K	28000 - 2FFFF
SA13	64K/32K	30000 - 37FFF
SA14	64K/32K	38000 - 3FFFF
SA15	64K/32K	40000 - 47FFF
SA16	64K/32K	48000 - 4FFFF
SA17	64K/32K	50000 - 57FFF
SA18	64K/32K	58000 - 5FFFF
SA19	64K/32K	60000 - 67FFF
SA20	64K/32K	68000 - 6FFFF
SA21	64K/32K	70000 - 77FFF
SA22	64K/32K	78000 - 7FFFF
SA23	64K/32K	80000 - 87FFF
SA24	64K/32K	88000 - 8FFFF
SA25	64K/32K	90000 - 97FFF
SA26	64K/32K	98000 - 9FFFF
SA27	64K/32K	A0000 - A7FFF
SA28	64K/32K	A8000 - AFFFF
SA29	64K/32K	B0000 - B7FFF
SA30	64K/32K	B8000 - BFFFF
SA31	64K/32K	C0000 - C7FFF
SA32	64K/32K	C8000 - CFFFF
SA33	64K/32K	D0000 - D7FFF
SA34	64K/32K	D8000 - DFFFF
SA35	64K/32K	E0000 - E7FFF
SA36	64K/32K	E8000 - EFFFF
SA37	64K/32K	F0000 - F7FFF

## 24. AT49BV320D Sector Address Table (Continued)

Sector	Size (Bytes/Words)	Address Range (A20 - A0)
SA38	64K/32K	F8000 - FFFFF
SA39	64K/32K	100000 - 107FFF
SA40	64K/32K	108000 - 10FFFF
SA41	64K/32K	110000 - 117FFF
SA42	64K/32K	118000 - 11FFFF
SA43	64K/32K	120000 - 127FFF
SA44	64K/32K	128000 - 12FFFF
SA45	64K/32K	130000 - 137FFF
SA46	64K/32K	138000 - 13FFFF
SA47	64K/32K	140000 - 147FFF
SA48	64K/32K	148000 - 14FFFF
SA49	64K/32K	150000 - 157FFF
SA50	64K/32K	158000 - 15FFFF
SA51	64K/32K	160000 - 167FFF
SA52	64K/32K	168000 - 16FFFF
SA53	64K/32K	170000 - 177FFF
SA54	64K/32K	178000 - 17FFFF
SA55	64K/32K	180000 - 187FFF
SA56	64K/32K	188000 - 18FFFF
SA57	64K/32K	190000 - 197FFF
SA58	64K/32K	198000 - 19FFFF
SA59	64K/32K	1A0000 - 1A7FFF
SA60	64K/32K	1A8000 - 1AFFFF
SA61	64K/32K	1B0000 - 1B7FFF
SA62	64K/32K	1B8000 - 1BFFFF
SA63	64K/32K	1C0000 - 1C7FFF
SA64	64K/32K	1C8000 - 1CFFFF
SA65	64K/32K	1D0000 - 1D7FFF
SA66	64K/32K	1D8000 - 1DFFFF
SA67	64K/32K	1E0000 - 1E7FFF
SA68	64K/32K	1E8000 - 1EFFFF
SA69	64K/32K	1F0000 - 1F7FFF
SA70	64K/32K	1F8000 - 1FFFFF

**25. AT49BV320DT – Sector Address Table**

Sector	Size (Bytes/Words)	Address Range (A20 - A0)
SA0	64K/32K	00000 - 07FFF
SA1	64K/32K	08000 - 0FFFF
SA2	64K/32K	10000 - 17FFF
SA3	64K/32K	18000 - 1FFFF
SA4	64K/32K	20000 - 27FFF
SA5	64K/32K	28000 - 2FFFF
SA6	64K/32K	30000 - 37FFF
SA7	64K/32K	38000 - 3FFFF
SA8	64K/32K	40000 - 47FFF
SA9	64K/32K	48000 - 4FFFF
SA10	64K/32K	50000 - 57FFF
SA11	64K/32K	58000 - 5FFFF
SA12	64K/32K	60000 - 67FFF
SA13	64K/32K	68000 - 6FFFF
SA14	64K/32K	70000 - 77FFF
SA15	64K/32K	78000 - 7FFFF
SA16	64K/32K	80000 - 87FFF
SA17	64K/32K	88000 - 8FFFF
SA18	64K/32K	90000 - 97FFF
SA19	64K/32K	98000 - 9FFFF
SA20	64K/32K	A0000 - A7FFF
SA21	64K/32K	A8000 - AFFFF
SA22	64K/32K	B0000 - B7FFF
SA23	64K/32K	B8000 - BFFFF
SA24	64K/32K	C0000 - C7FFF
SA25	64K/32K	C8000 - CFFFF
SA26	64K/32K	D0000 - D7FFF
SA27	64K/32K	D8000 - DFFFF
SA28	64K/32K	E0000 - E7FFF
SA29	64K/32K	E8000 - EFFFF
SA30	64K/32K	F0000 - F7FFF
SA31	64K/32K	F8000 - FFFFF
SA32	64K/32K	100000 - 107FFF
SA33	64K/32K	108000 - 10FFFF
SA34	64K/32K	110000 - 117FFF
SA35	64K/32K	118000 - 11FFFF
SA36	64K/32K	120000 - 127FFF
SA37	64K/32K	128000 - 12FFFF



## 25. AT49BV320DT – Sector Address Table (Continued)

Sector	Size (Bytes/Words)	Address Range (A20 - A0)
SA38	64K/32K	130000 - 137FFF
SA39	64K/32K	138000 - 13FFFF
SA40	64K/32K	140000 - 147FFF
SA41	64K/32K	148000 - 14FFFF
SA42	64K/32K	150000 - 157FFF
SA43	64K/32K	158000 - 15FFFF
SA44	64K/32K	160000 - 167FFF
SA45	64K/32K	168000 - 16FFFF
SA46	64K/32K	170000 - 177FFF
SA47	64K/32K	178000 - 17FFFF
SA48	64K/32K	180000 - 187FFF
SA49	64K/32K	188000 - 18FFFF
SA50	64K/32K	190000 - 197FFF
SA51	64K/32K	198000 - 19FFFF
SA52	64K/32K	1A0000 - 1A7FFF
SA53	64K/32K	1A8000 - 1AFFFF
SA54	64K/32K	1B0000 - 1B7FFF
SA55	64K/32K	1B8000 - 1BFFFF
SA56	64K/32K	1C0000 - 1C7FFF
SA57	64K/32K	1C8000 - 1CFFFF
SA58	64K/32K	1D0000 - 1D7FFF
SA59	64K/32K	1D8000 - 1DFFFF
SA60	64K/32K	1E0000 - 1E7FFF
SA61	64K/32K	1E8000 - 1EFFFF
SA62	64K/32K	1F0000 - 1F7FFF
SA63	8K/4K	1F8000 - 1F8FFF
SA64	8K/4K	1F9000 - 1F9FFF
SA65	8K/4K	1FA000 - 1FAFFF
SA66	8K/4K	1FB000 - 1FBFFF
SA67	8K/4K	1FC000 - 1FCFFF
SA68	8K/4K	1FD000 - 1FDFFF
SA69	8K/4K	1FE000 - 1FEFFF
SA70	8K/4K	1FF000 - 1FFFFF

## 26. DC and AC Operating Range

		AT49BV320D(T)-70
Operating Temperature (Case)	Ind.	-40°C - 85°C
V <sub>CC</sub> Power Supply		2.65V to 3.6V

## 27. Operating Modes

Mode	$\overline{CE}$	$\overline{OE}$	$\overline{WE}$	$\overline{RESET}$	V <sub>PP</sub> <sup>(1)</sup>	Ai	I/O
Read	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IH</sub>	X <sup>(2)</sup>	Ai	D <sub>OUT</sub>
Program/Erase <sup>(3)</sup>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IHPP</sub> <sup>(4)</sup>	Ai	D <sub>IN</sub>
Standby/Program Inhibit	V <sub>IH</sub>	X <sup>(2)</sup>	X	V <sub>IH</sub>	X	X	High-Z
Program Inhibit	X	X	V <sub>IH</sub>	V <sub>IH</sub>	X		
	X	V <sub>IL</sub>	X	V <sub>IH</sub>	X		
	X	X	X	V <sub>IH</sub>	V <sub>ILPP</sub> <sup>(5)</sup>		
Output Disable	X	V <sub>IH</sub>	X	V <sub>IH</sub>	X		High-Z
Reset	X	X	X	V <sub>IL</sub>	X	X	High-Z
Product Identification Software				V <sub>IH</sub>		A0 = V <sub>IL</sub> , A1 - A20 = V <sub>IL</sub>	Manufacturer Code <sup>(6)</sup>
						A0 = V <sub>IH</sub> , A1 - A20 = V <sub>IL</sub>	Device Code <sup>(6)</sup>

Notes: 1. The VPP pin can be tied to V<sub>CC</sub>. For faster program operations, V<sub>PP</sub> can be set to 9.5V ± 0.5V.

2. X can be V<sub>IL</sub> or V<sub>IH</sub>.

3. Refer to AC programming waveforms on [page 26](#).

4. V<sub>IHPP</sub> (min) = 1.65V.

5. V<sub>ILPP</sub> (max) = 0.4V.

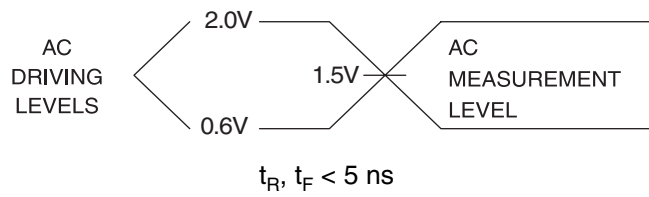
6. Manufacturer Code: 001FH, Device Code: 90C5H – AT49BV320D; 90C4H – AT49BV320DT

## 28. DC Characteristics

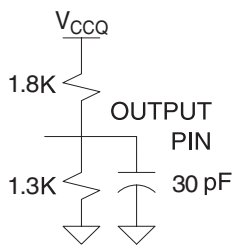
Symbol	Parameter	Condition	Min	Typ	Max	Units
$I_{LI}$	Input Load Current	$V_{IN} = 0V \text{ to } V_{CC}$			2	$\mu A$
$I_{LO}$	Output Leakage Current	$V_{IO} = 0V \text{ to } V_{CC}$			2	$\mu A$
$I_{SB}$	$V_{CC}$ Standby Current CMOS	$\overline{CE} = V_{CC} - 0.3V \text{ to } V_{CC}$		15	25	$\mu A$
$I_{CC}^{(1)}$	$V_{CC}$ Active Read Current	$f = 5 \text{ MHz}; I_{OUT} = 0 \text{ mA}$		10	15	mA
$I_{CC1}$	$V_{CC}$ Programming Current				25	mA
$I_{PP1}$	$V_{PP}$ Input Load Current				10	$\mu A$
$V_{IL}$	Input Low Voltage				0.6	V
$V_{IH}$	Input High Voltage		$V_{CCQ} - 0.6$			V
$V_{OL}$	Output Low Voltage	$I_{OL} = 2.1 \text{ mA}$			0.45	V
$V_{OH}$	Output High Voltage	$I_{OH} = -100 \mu A$	$V_{CCQ} - 0.1$			V

Note: 1. In the erase mode,  $I_{CC}$  is 25 mA.

### 29. Input Test Waveforms and Measurement Level



### 30. Output Test Load



### 31. Pin Capacitance

$f = 1 \text{ MHz}, T = 25^\circ\text{C}^{(1)}$

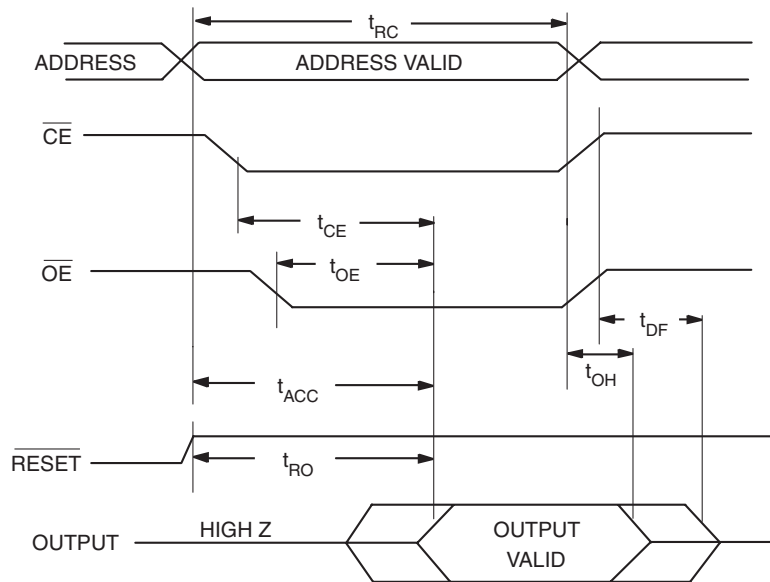
Symbol	Typ	Max	Units	Conditions
$C_{IN}$	4	6	pF	$V_{IN} = 0V$
$C_{OUT}$	8	12	pF	$V_{OUT} = 0V$

Note: This parameter is characterized and is not 100% tested.

## 32. AC Read Characteristics

Symbol	Parameter	AT49BV320D(T)-70		Units
		Min	Max	
$t_{RC}$	Read Cycle Time	70		ns
$t_{ACC}$	Address to Output Delay		70	ns
$t_{CE}^{(1)}$	$\overline{CE}$ to Output Delay		70	ns
$t_{OE}^{(2)}$	$\overline{OE}$ to Output Delay	0	20	ns
$t_{DF}^{(3)(4)}$	$\overline{CE}$ or $\overline{OE}$ to Output Float	0	25	ns
$t_{OH}$	Output Hold from $\overline{OE}$ , $\overline{CE}$ or Address, whichever occurred first	0		ns
$t_{RO}$	$\overline{RESET}$ to Output Delay		100	ns

## 33. AC Read Waveforms<sup>(1)(2)(3)(4)</sup>



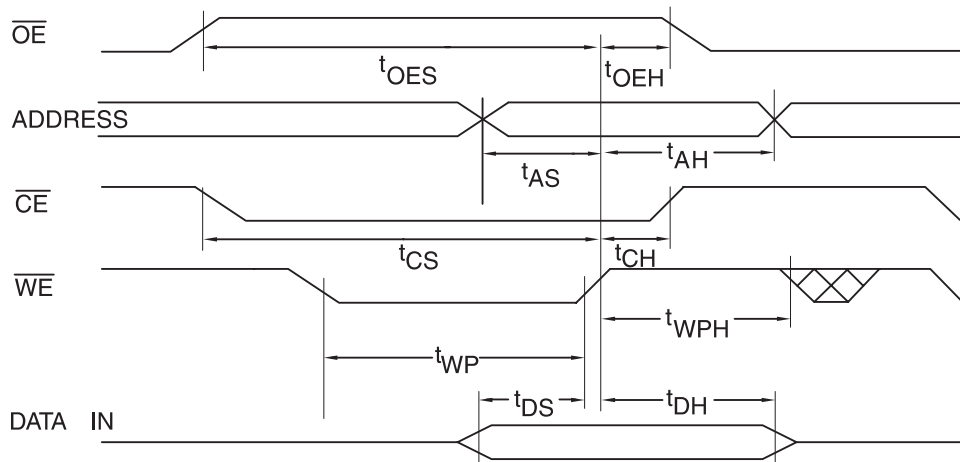
- Notes:
- $\overline{CE}$  may be delayed up to  $t_{ACC} - t_{CE}$  after the address transition without impact on  $t_{ACC}$ .
  - $\overline{OE}$  may be delayed up to  $t_{CE} - t_{OE}$  after the falling edge of  $\overline{CE}$  without impact on  $t_{CE}$  or by  $t_{ACC} - t_{OE}$  after an address change without impact on  $t_{ACC}$ .
  - $t_{DF}$  is specified from  $\overline{OE}$  or  $\overline{CE}$ , whichever occurs first ( $CL = 5 \text{ pF}$ ).
  - This parameter is characterized and is not 100% tested.

### 34. AC Word Load Characteristics

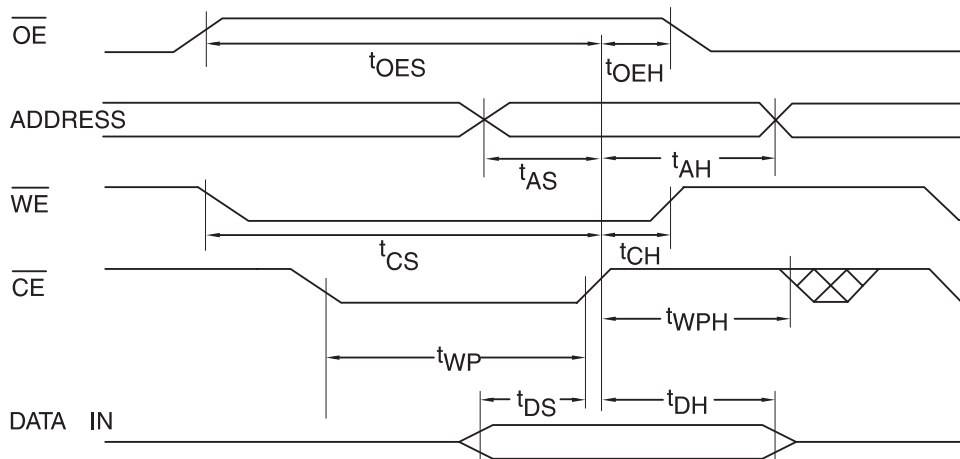
Symbol	Parameter	Min	Max	Units
$t_{AS}, t_{OES}$	Address, $\overline{OE}$ Setup Time	20		ns
$t_{AH}$	Address Hold Time	0		ns
$t_{CS}$	Chip Select Setup Time	0		ns
$t_{CH}$	Chip Select Hold Time	0		ns
$t_{WP}$	Write Pulse Width ( $\overline{WE}$ or $\overline{CE}$ )	25		ns
$t_{WPH}$	Write Pulse Width High	15		ns
$t_{DS}$	Data Setup Time	25		ns
$t_{DH}, t_{OEH}$	Data, $\overline{OE}$ Hold Time	0		ns

### 35. AC Word Load Waveforms

#### 35.1 $\overline{WE}$ Controlled



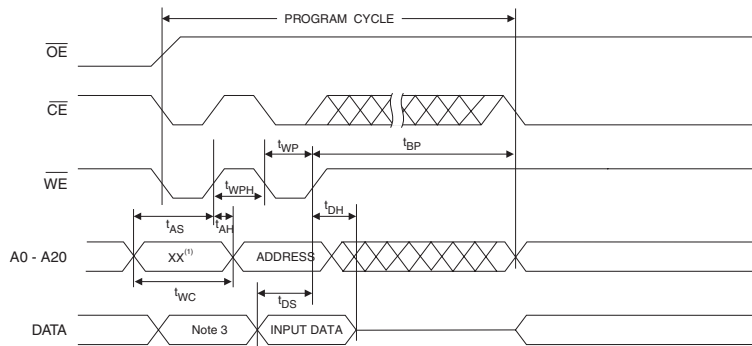
#### 35.2 $\overline{CE}$ Controlled



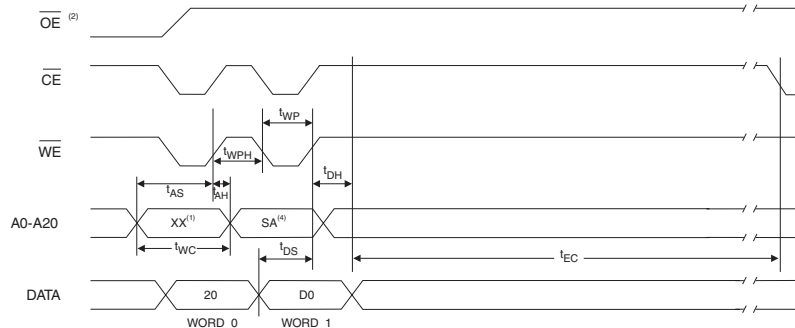
## 36. Program Cycle Characteristics

Symbol	Parameter	Min	Typ	Max	Units
$t_{BP}$	Word Programming Time		10	120	$\mu s$
$t_{BPD}$	Word Programming Time in Dual Programming Mode		5	60	$\mu s$
$t_{AS}$	Address Setup Time	20			ns
$t_{AH}$	Address Hold Time	0			ns
$t_{DS}$	Data Setup Time	25			ns
$t_{DH}$	Data Hold Time	0			ns
$t_{WP}$	Write Pulse Width	25			ns
$t_{WPH}$	Write Pulse Width High	15			ns
$t_{WC}$	Write Cycle Time	70			ns
$t_{RP}$	$\overline{Reset}$ Pulse Width	500			ns
$t_{SEC1}$	Sector Erase Cycle Time (4K Word Sectors)		0.1	2	seconds
$t_{SEC2}$	Sector Erase Cycle Time (32K Word Sectors)		0.5	6.0	seconds
$t_{ES}$	Erase Suspend Time			15	$\mu s$
$t_{PS}$	Program Suspend Time			10	$\mu s$

## 37. Program Cycle Waveforms



## 38. Sector Erase Cycle Waveforms



- Notes:
1. Any address can be used to load the data.
  2.  $\overline{OE}$  must be high only when  $\overline{WE}$  and  $\overline{CE}$  are both low.
  3. The data can be 40H or 10H.
  4. The address depends on what sector is to be erased.

### 39. Common Flash Interface Definition Table

Address	AT49BV320DT	AT49BV320D	Comments
10h	0051h	0051h	“Q”
11h	0052h	0052h	“R”
12h	0059h	0059h	“Y”
13h	0003h	0003h	
14h	0000h	0000h	
15h	0041h	0041h	
16h	0000h	0000h	
17h	0000h	0000h	
18h	0000h	0000h	
19h	0000h	0000h	
1Ah	0000h	0000h	
1Bh	0027h	0027h	VCC min write/erase
1Ch	0036h	0036h	VCC max write/erase
1Dh	0090h	0090h	VPP min voltage
1Eh	00A0h	00A0h	VPP max voltage
1Fh	0004h	0004h	Typ word write – 10 $\mu$ s
20h	0002h	0002h	Typ dual word program time – 5 $\mu$ s
21h	0009h	0009h	Typ sector erase, 500 ms
22h	0000h	0000h	Typ chip erase, not supported
23h	0004h	0004h	Max word write/typ time
24h	0004h	0004h	Max dual word program time/typ time
25h	0004h	0004h	Max sector erase/typ sector erase
26h	0000h	0000h	Max chip erase/ typ chip erase
27h	0016h	0016h	Device size
28h	0001h	0001h	x16 device
29h	0000h	0000h	x16 device
2Ah	0002h	0002h	Maximum number of bytes in multiple byte write = 4
2Bh	0000h	0000h	Maximum number of bytes in multiple byte write = 4
2Ch	0002h	0002h	2 regions, x = 2
2Dh	003Eh	0007h	64K bytes, Y = 62 (Top); 8K bytes, Y = 7 (Bottom)
2Eh	0000h	0000h	64K bytes, Y = 62 (Top); 8K bytes, Y = 7 (Bottom)
2Fh	0000h	0020h	64K bytes, Z = 256 (Top); 8K bytes, Z = 32 (Bottom)
30h	0001h	0000h	64K bytes, Z = 256 (Top); 8K bytes, Z = 32 (Bottom)
31h	0007h	003Eh	8K bytes, Y = 7 (Top); 64K bytes, Y = 62 (Bottom)
32h	0000h	0000h	8K bytes, Y = 7 (Top); 64K bytes, Y = 62 (Bottom)
33h	0020h	0000h	8K bytes, Z = 32 (Top); 64K bytes, Z = 256 (Bottom)
34h	0000h	0001h	8K bytes, Z = 32 (Top); 64K bytes, Z = 256 (Bottom)

### 39. Common Flash Interface Definition Table (Continued)

Address	AT49BV320DT	AT49BV320D	Comments
<b>VENDOR SPECIFIC EXTENDED QUERY</b>			
41h	0050h	0050h	"P"
42h	0052h	0052h	"R"
43h	0049h	0049h	"I"
44h	0031h	0031h	Major version number, ASCII
45h	0030h	0030h	Minor version number, ASCII
46h	0086h	0086h	Bit 0 – chip erase supported, 0 – no, 1 – yes Bit 1 – erase suspend supported, 0 – no, 1 – yes Bit 2 – program suspend supported, 0 – no, 1 – yes Bit 3 – simultaneous operations supported, 0 – no, 1 – yes Bit 4 – burst mode read supported, 0 – no, 1 – yes Bit 5 – page mode read supported, 0 – no, 1 – yes Bit 6 – queued erase supported, 0 – no, 1 – yes Bit 7 – protection bits supported, 0 – no, 1 – yes
47h	0000h	0001h	Bit 8 – top ("0") or bottom ("1") boot sector device undefined bits are "0"
48h	0000h	0000h	Bit 0 – 4 word linear burst with wrap around, 0 – no, 1 – yes Bit 1 – 8 word linear burst with wrap around, 0 – no, 1 – yes Bit 2 – continuous burst, 0 – no, 1 – yes Undefined bits are "0"
49h	0000h	0000h	Bit 0 – 4 word page, 0 – no, 1 – yes Bit 1 – 8 word page, 0 – no, 1 – yes Undefined bits are "0"
4Ah	0080h	0080h	Location of protection register lock byte, the section's first byte
4Bh	0003h	0003h	# of bytes in the factory prog section of prot register – 2*n
4Ch	0003h	0003h	# of bytes in the user prog section of prot register – 2*n

## 40. Ordering Information

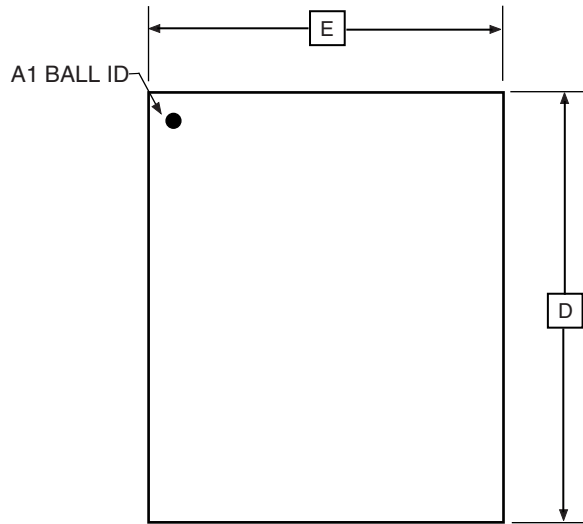
### 40.1 Green Package (Pb/Halide-free)

$t_{ACC}$ (ns)	$I_{CC}$ (mA)		Ordering Code	Package	Operation Range
	Active	Standby			
70	25	0.025	AT49BV320D-70CU AT49BV320D-70TU	47C1 48T	Industrial (-40° to 85° C)
			AT49BV320DT-70CU AT49BV320DT-70TU	47C1 48T	

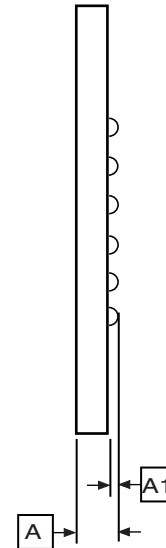
Package Type	
<b>47C1</b>	47-ball, Plastic Chip-Size Ball Grid Array Package (CBGA)
<b>48T</b>	48-lead, Plastic Thin Small Outline Package (TSOP)

## 41. Packaging Information

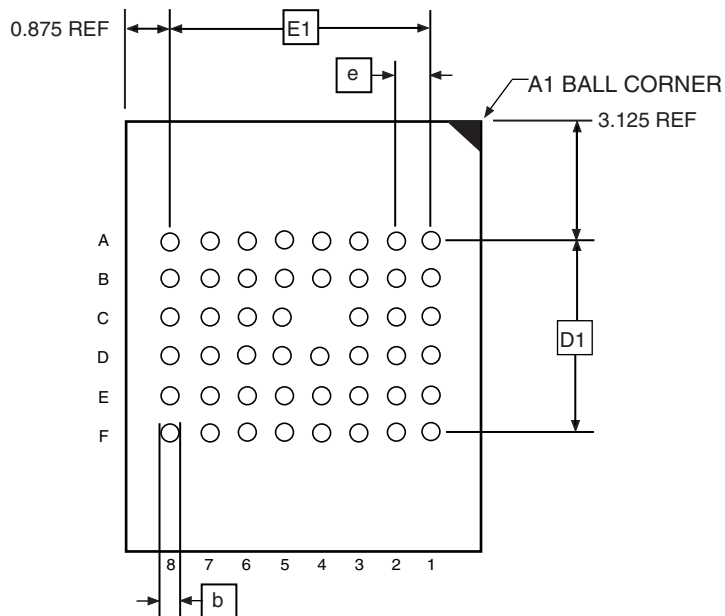
### 41.1 47C1 – CBGA



TOP VIEW



SIDE VIEW



BOTTOM VIEW

COMMON DIMENSIONS  
(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
E	6.90	7.00	7.10	
E1	5.25 TYP			
D	9.90	10.00	10.10	
D1	3.75 TYP			
A	—	—	1.00	
A1	0.22	—	—	
e	0.75 BSC			
b	0.35 TYP			

7/2/03



2325 Orchard Parkway  
San Jose, CA 95131

#### TITLE

**47C1**, 47-ball (8 x 6 Array), 0.75 mm Pitch,  
7.0 x 10.0 x 1.0 mm Chip-scale Ball Grid Array Package (CBGA)

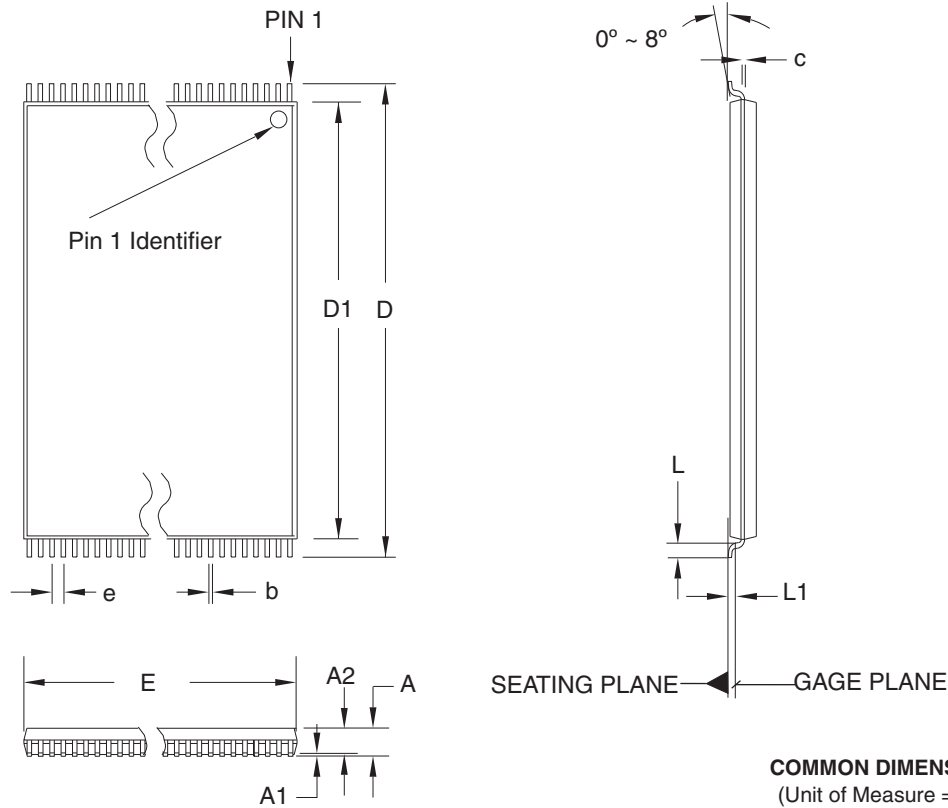
#### DRAWING NO.

47C1

#### REV.

A

41.2 48T – TSOP



**COMMON DIMENSIONS**  
(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
A	—	—	1.20	
A1	0.05	—	0.15	
A2	0.95	1.00	1.05	
D	19.80	20.00	20.20	
D1	18.30	18.40	18.50	Note 2
E	11.90	12.00	12.10	Note 2
L	0.50	0.60	0.70	
L1	0.25 BASIC			
b	0.17	0.22	0.27	
c	0.10	—	0.21	
e	0.50 BASIC			

- Notes:
1. This package conforms to JEDEC reference MO-142, Variation DD.
  2. Dimensions D1 and E do not include mold protrusion. Allowable protrusion on E is 0.15 mm per side and on D1 is 0.25 mm per side.
  3. Lead coplanarity is 0.10 mm maximum.

10/18/01



2325 Orchard Parkway  
San Jose, CA 95131

**TITLE**

**48T**, 48-lead (12 x 20 mm Package) Plastic Thin Small Outline  
Package, Type I (TSOP)

**DRAWING NO.**

48T

**REV.**

B



## 42. Revision History

Revision No.	History
Revision A – Sept. 2005	<ul style="list-style-type: none"> <li>Initial Release</li> </ul>
Revision B – Oct. 2005	<ul style="list-style-type: none"> <li>Added Top Boot version.</li> <li>Added Sector Address Table for the AT49BV320DT.</li> <li>Added CFI information for the AT49BV320DT.</li> <li>Modified Program Suspend/Resume Procedure on page 11 to match the flow chart.</li> <li>Modified Erase Suspend/Resume Procedure on page 13 to match the flow chart.</li> </ul>
Revision C – Nov. 2005	<ul style="list-style-type: none"> <li>Added CBGA Package Option.</li> <li>Changed the CFI values of addresses 20h &amp; 24h to 0002h and 0004h, respectively.</li> </ul>
Revision D – Feb. 2006	<ul style="list-style-type: none"> <li>Changed the AT49BV320DT CFI values of addresses 23h &amp; 25h to 0004h and 0004h, respectively.</li> </ul>



## Atmel Corporation

2325 Orchard Parkway  
San Jose, CA 95131, USA  
Tel: 1(408) 441-0311  
Fax: 1(408) 487-2600

## Regional Headquarters

### Europe

Atmel Sarl  
Route des Arsenalux 41  
Case Postale 80  
CH-1705 Fribourg  
Switzerland  
Tel: (41) 26-426-5555  
Fax: (41) 26-426-5500

### Asia

Room 1219  
Chinachem Golden Plaza  
77 Mody Road Tsimshatsui  
East Kowloon  
Hong Kong  
Tel: (852) 2721-9778  
Fax: (852) 2722-1369

### Japan

9F, Tonetsu Shinkawa Bldg.  
1-24-8 Shinkawa  
Chuo-ku, Tokyo 104-0033  
Japan  
Tel: (81) 3-3523-3551  
Fax: (81) 3-3523-7581

## Atmel Operations

### Memory

2325 Orchard Parkway  
San Jose, CA 95131, USA  
Tel: 1(408) 441-0311  
Fax: 1(408) 436-4314

### Microcontrollers

2325 Orchard Parkway  
San Jose, CA 95131, USA  
Tel: 1(408) 441-0311  
Fax: 1(408) 436-4314

La Chantrerie  
BP 70602  
44306 Nantes Cedex 3, France  
Tel: (33) 2-40-18-18-18  
Fax: (33) 2-40-18-19-60

### ASIC/ASSP/Smart Cards

Zone Industrielle  
13106 Rousset Cedex, France  
Tel: (33) 4-42-53-60-00  
Fax: (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd.  
Colorado Springs, CO 80906, USA  
Tel: 1(719) 576-3300  
Fax: 1(719) 540-1759

Scottish Enterprise Technology Park  
Maxwell Building  
East Kilbride G75 0QR, Scotland  
Tel: (44) 1355-803-000  
Fax: (44) 1355-242-743

### RF/Automotive

Theresienstrasse 2  
Postfach 3535  
74025 Heilbronn, Germany  
Tel: (49) 71-31-67-0  
Fax: (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd.  
Colorado Springs, CO 80906, USA  
Tel: 1(719) 576-3300  
Fax: 1(719) 540-1759

### Biometrics/Imaging/Hi-Rel MPU/ High Speed Converters/RF Datacom

Avenue de Rochepleine  
BP 123  
38521 Saint-Egreve Cedex, France  
Tel: (33) 4-76-58-30-00  
Fax: (33) 4-76-58-34-80

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## Literature Requests

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